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a first substrate;
a connection wiring formed over the first substrate;
an EL element formed over the first substrate;
an absorption film formed over the EL element;
a passivation film formed over the connection wiring and the absorption film; and
a sealing substrate connected to the first substrate through a sealant,
wherein the EL element is provided in a space surrounded by the first substrate, the
sealant, and the sealing substrate; and
wherein the connection wiring and the passivation film extend beyond the sealant.

7. (previously presented) The light emitting device according to claim 6, wherein the
absorption film is a hygroscopic film.

8. (previously presented) The light emitting device according to claim 6, wherein the
absorption film comprises alkaline-earth metal.

9. (previously presented) The light emitting device according to claim 6, wherein the
absorption film has 1 to 3 μm thickness.

10. (previously presented) The light emitting device according to claim 6, wherein the
sealant is not overlapped with the absorption film.

11. (previously presented) The light emitting device according to claim 6, wherein the
light emitting device is one selected from the group consisting of a video camera, a digital
camera, a goggle type display, a navigation system, an audio apparatus, a note type personal
computer, a game apparatus, a portable apparatus, and an image play back device equipped with
a recording medium.

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12. (previously presented) A light emitting device comprising:
a first substrate;
a connection wiring formed over the first substrate;
an EL element formed over the first substrate, the EL element comprising an anode, an EL layer, and a cathode;
an absorption film formed over the cathode;
a passivation film formed over the connection wiring and the absorption film; and
a sealing substrate connected to the first substrate through a sealant,
wherein the connection wiring and the passivation film extend beyond the sealant.

13. (previously presented) The light emitting device according to claim 12, wherein the absorption film is a hygroscopic film.

14. (previously presented) The light emitting device according to claim 12, wherein the absorption film comprises alkaline-earth metal.

15. (previously presented) The light emitting device according to claim 12, wherein the absorption film has 1 to 3 μm thickness.

16. (previously presented) The light emitting device according to claim 12, wherein the absorption film is formed over the anode, and the EL layer, the cathode, and the absorption film are successively formed under an inert gas atmosphere.

17. (previously presented) The light emitting device according to claim 12, wherein the light emitting device is one selected from the group consisting of a video camera, a digital camera, a goggle type display, a navigation system, an audio apparatus, a note type personal computer, a game apparatus, a portable apparatus, and an image play back device equipped with a recording medium.

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18. (previously presented) A light emitting device comprising:
a substrate;
a TFT formed over the substrate;
an EL element electrically connected with the TFT; and
an absorption film formed over the EL element,
wherein the EL element is interposed between the substrate and the absorption film.

19. (previously presented) The light emitting device according to claim 18, wherein the absorption film is a hygroscopic film.

20. (previously presented) The light emitting device according to claim 18, wherein the absorption film comprises alkaline-earth metal.

21. (previously presented) The light emitting device according to claim 18, wherein the absorption film has 1 to 3 μm thickness.

22. (previously presented) The light emitting device according to claim 18, wherein the light emitting device is one selected from the group consisting of a video camera, a digital camera, a goggle type display, a navigation system, an audio apparatus, a note type personal computer, a game apparatus, a portable apparatus, and an image play back device equipped with a recording medium.

23. (previously presented) A light emitting device comprising:
a first substrate;
a connection wiring formed over the first substrate;
an EL element formed over the first substrate;
an inorganic hygroscopic film formed over the EL element for absorbing moisture;

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a passivation film formed over the connection wiring and the inorganic hygroscopic film;
and
a sealing substrate connected to the first substrate through a sealant,
wherein the EL element is enclosed by the first substrate and the inorganic hygroscopic
film; and
wherein the connection wiring and the passivation film extend beyond the sealant.

24. (previously presented) The light emitting device according to claim 23, wherein the inorganic hygroscopic film comprises alkaline-earth metal.

25. (previously presented) The light emitting device according to claim 23, wherein the inorganic hygroscopic film has 1 to 3 μm thickness.

26. (previously presented) The light emitting device according to claim 23, wherein the device is one selected from the group consisting of a video camera, a digital camera, a goggle type display, a navigation system, an audio apparatus, a note type personal computer, a game apparatus, a portable apparatus, and an image play back device equipped with a recording medium.

27. (previously presented) A light emitting device comprising:
a substrate;
an EL element comprising an organic light emitting layer formed over the substrate;
a barrier film covering the EL element;
an inorganic hygroscopic film formed on the barrier film; and
a passivation film on the inorganic hygroscopic film.

28. (previously presented) The light emitting device according to claim 27, wherein the EL element further comprises an anode, a hole injection layer, a hole transfer layer, and a

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cathode

29. (previously presented) The light emitting device according to claim 27, wherein the barrier film comprises a material selected from the group consisting of carbon, silicon oxide, silicon nitride, and copper phthalocyanine.

30. (previously presented) The light emitting device according to claim 27, wherein the inorganic hygroscopic film comprises alkaline-earth metal.

31. (previously presented) The light emitting device according to claim 27, wherein the inorganic hygroscopic film has 1 to 3 μm thickness.

32. (previously presented) The light emitting device according to claim 27, wherein the light emitting device is one selected from the group consisting of a video camera, a digital camera, a goggle type display, a navigation system, an audio apparatus, a note type personal computer, a game apparatus, a portable apparatus, and an image play back device equipped with a recording medium.

33. (previously presented) A light emitting device comprising:
a first substrate;
an EL element comprising an organic light emitting layer formed over the first substrate;
a barrier film covering the EL element;
an inorganic hygroscopic film formed on the barrier film;
a passivation film formed on the inorganic hygroscopic film; and
a second substrate opposed to the first substrate with the EL element disposed therebetween, wherein a space between the first substrate and second substrate is hermetically sealed by a sealant.

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34. (previously presented) The light emitting device according to claim 33, wherein a metal film covers the sealant and the second substrate.

35. (previously presented) The light emitting device according to claim 34, wherein the metal film comprises a material selected from the group consisting of Al and Mg.

36. (previously presented) The light emitting device according to claim 33, wherein the space is filled with an inert gas selected from the group consisting of nitrogen and a noble gas.

37. (previously presented) The light emitting device according to claim 33, wherein the EL element further comprises an anode, a hole injection layer, a hole transfer layer, and a cathode.

38. (previously presented) The light emitting device according to claim 33, wherein the barrier film comprises a material selected from the group consisting of carbon, silicon oxide, silicon nitride, and copper phthalocyanine.

39. (previously presented) The light emitting device according to claim 33, wherein the inorganic hygroscopic film comprises alkaline-earth metal.

40. (previously presented) The light emitting device according to claim 33, wherein the inorganic hygroscopic film has 1 to 3 μm thickness.

41. (previously presented) The light emitting device according to claim 33, wherein the light emitting device is one selected from the group consisting of a video camera, a digital camera, a goggle type display, a navigation system, an audio apparatus, a note type personal computer, a game apparatus, a portable apparatus, and an image play back device equipped with a recording medium.

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42. (previously presented) A light emitting device comprising:
a first substrate;
a plurality of switching elements formed over the first substrate, each of the plurality of switching elements comprising a TFT;
a plurality of EL elements formed over the first substrate and operationally connected to the plurality of switching elements, each of the plurality of EL elements comprising an organic light emitting layer;
a driver circuit comprising TFTs formed over the first substrate;
an inorganic hygroscopic film formed over the plurality of EL elements and the driver circuit; and
a second substrate opposed to the first substrate with the plurality of EL elements disposed therebetween, wherein a space between the first substrate and second substrate is hermetically sealed by a sealant.

43. (previously presented) The light emitting device according to claim 42, wherein a metal film covers the sealant and the second substrate.

44. (previously presented) The light emitting device according to claim 43, wherein the metal film comprises a material selected from the group consisting of Al and Mg.

45. (previously presented) The light emitting device according to claim 42, wherein the space is filled with an inert gas selected from the group consisting of nitrogen and a noble gas.

46. (previously presented) The light emitting device according to claim 42, wherein the EL element further comprises an anode, a hole injection layer, a hole transfer layer, and a cathode.

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47. (previously presented) The light emitting device according to claim 42, wherein the inorganic hygroscopic film comprises alkaline-earth metal.

48. (previously presented) The light emitting device according to claim 42, wherein the inorganic hygroscopic film has 1 to 3 μm thickness.

49. (previously presented) The light emitting device according to claim 42, wherein the light emitting device is one selected from the group consisting of a video camera, a digital camera, a goggle type display, a navigation system, an audio apparatus, a note type personal computer, a game apparatus, a portable apparatus, and an image play back device equipped with a recording medium.

50. (withdrawn) A method of manufacturing a light emitting device comprising the steps of:
providing a film formation apparatus;
forming an EL layer over a substrate in the film formation apparatus;
forming an inorganic hygroscopic film over the EL layer in the film formation apparatus;
wherein the substrate is prevented from contacting an air outside of the film formation apparatus after the formation of the EL layer and until the formation of the inorganic hygroscopic film is finished.

51. (withdrawn) A method of manufacturing a light emitting device according to claim 50, wherein the inorganic hygroscopic film comprises alkaline-earth metal.

52. (withdrawn) A method of manufacturing a light emitting device according to claim 50, wherein the inorganic film has 1 to 3 μm thickness.

53. (withdrawn) A method of manufacturing a light emitting device comprising the steps

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of:

providing a film formation apparatus having a plurality of chambers;
forming an EL layer over a substrate in one chamber of the film formation apparatus;
forming an inorganic hygroscopic film over the EL layer in an another chamber of the film formation apparatus;
wherein the steps from forming the EL layer to forming the inorganic hygroscopic film are performed without exposing the substrate to moisture and oxygen.

54. (withdrawn) A method of manufacturing a light emitting device according to claim 12, wherein the inorganic hygroscopic film comprises alkaline-earth metal.

55. (withdrawn) A method of manufacturing a light emitting device according to claim 12, wherein the inorganic film has 1 to 3 μm thickness.

56. (new) A light emitting device comprising:
a substrate;
an EL element formed over the substrate;
a barrier film covering the EL element;
an absorption film formed on the barrier film; and
a passivation film formed on the absorption film,
wherein light emitted from the EL element is discharged to a side of the EL element closest to the substrate.

57. (new) The light emitting device according to claim 56, wherein the absorption film is a hygroscopic film.

58. (new) The light emitting device according to claim 56, wherein the absorption film comprises alkaline-earth metal.

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59. (new) The light emitting device according to claim 56, wherein the absorption film has 1 to 3 μm thickness.

60. (new) The light emitting device according to claim 56, wherein the light emitting device is one selected from the group consisting of a video camera, a digital camera, a goggle type display, a navigation system, an audio apparatus, a note type personal computer, a game apparatus, a portable apparatus, and an image play back device equipped with a recording medium.